MC14419

2-OF-8 KEYPAD-TO-BINARY ENCODER

3501 ED BLUESTEIN BLVD., AUSTIN, TEXAS 78721

The MC14419 is designed for phone dialer system applications, but finds many applications as a keypad-to-binary encoder. The device contains a 2-of-8 to binary encoder, a strobe generator, and an illegal state detector. The encoder has four row inputs and four column inputs, and is designed to accept inputs from 16 keyswitches arranged in a 4×4 matrix. For an output on the four data lines, one and only one row along with one and only one column input line must be activated. All other combinations are suppressed by the illegal state detector to eliminate false data output.

The strobe generator produces a strobe pulse when any of the 10 keys corresponding to numerals 0 through 9 are depressed. The strobe output can be used to eliminate erroneous data entry due to contact bounce. For a strobe output to occur, the key row and column input lines must remain stable for 80 clock pulses after activation. When the contact bounce has settled and 80 clock pulses have occurred, the output will be a single strobe pulse equal in width to that of the clock low state. The strobe generator will output one and only one pulse each time a numerical key is depressed. After the pulse has occurred, noise and bounce due to contact break will not cause another strobe pulse. With a 16 kHz input clock frequency, the pulse occurs 5 ms after the last bounce.

- Suppressed Output for Illegal Input Codes
- On-Chip Pullup Resistors for Row and Column Inputs
- Clock Input Conditioning Circuit
- Low Current Drain in Standby Mode
 5.0μA Typical @ 5.0 Vdc
- Subsystem Complement to the MC14408/14409 Phone Pulse Converter
- Codes for Numbers 0-9 Produce a Strobe Pulse
- One Key Rollover Feature

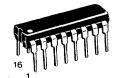
BLOCK DIAGRAM Q 15 Clock Row Inputs BCD Strobe Generator Detector Column C2 Inputs C3 0 14 Strobe **O** 13 2-of-8 Binary 0 12 Encoder Data and Outputs O 11 D2 Illegal Code Detector **→**010 D1 V_{DD} = Pin 16 VSS = Pin 8

CMOS

(LOW-POWER COMPLEMENTARY MOS)

2-OF-8 KEYPAD-TO-BINARY ENCODER

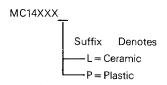




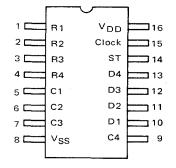
L SUFFIX
CERAMIC PACKAGE
CASE 620

P SUFFIX
PLASTIC PACKAGE
CASE 648

ORDERING INFORMATION



PIN ASSIGNMENT



This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit. For proper operation it is recommended that V_{in} and V_{out} be constrained to the range $V_{SS} \leqslant \{V_{in} \text{ or } V_{out}\} \leqslant V_{DD}.$

MAXIMUM RATINGS (Voltages referenced to V_{SS}, Pin 8.)

Rating	Symbol	Value	Unit	
DC Supply Voltage	VDD	+6.0 to -0.5	Vdc	
Input Voltage, All Inputs	V _{in}	V _{DD} + 0.5 to V _{SS} -0.5	Vdc	
DC Current Drain per Pin	ı	10	mAdc	
Operating Temperature Range	TA	-40 to +85	°C	
Storage Temperature Range	T _{stg}	-65 to +150	°C	

ELECTRICAL CHARACTERISTICS

LLLO I III O, IL O.	ELOTHICAE CHARACTERIOTICS										
Characteristic			V _{DD}	-40°C		25 ⁰ C			+85°C		
		Symbol		Min	Max	Min	Тур	Max	Min	Max	Unit
Supply Voltage Ope	rating Range	V _{DD}	-	3.0	6.0	3.0	5.0	6.0	3.0	6.0	Vdc
Output Voltage	"0" Level	V _{out}	5.0	-	0.01	_	0	0.01	- →	0.05	Vdc
	"1" Level		5.0	4.99	_	4.99	5.0	< <u>-</u> √	4.95		Vdc
Noise Immunity		V _{NL}	5.0	1.5	_	1.5	2.25	-	1.4	_	Vdc
(△V _{out} ≤ 0.8 Vo	lc)	v_{NH}	5.0	1.4		1.5	2.25	- ***	1.5	_	Vdc
Output Drive Currer (VOH = 2.5 Vdc		ГОН	5.0	-0.23	-	-0.20	-1.7	" _	-0.16	_	mAdc
(VOL = 0.4 Vdc)	Sink	lOL	5.0	0.23	_	0.20	0.78	-	0.16	_	mAdo
Input Leakage Curre (Vin = V _{DD})	ent	IH	5.0	_	_	_	, 10	_	-		pAdo
Pullup Resistor Sour (Row and Colum (V _{in} = V _{SS})		III.	5.0	265	460	190	250	330	125	215	μAdc
Input Capacitance (Vin = V _{SS})		C _{in}	_	-	1	_	5.0	***	_	_	pF
Standby Supply Cur		IDDS	3.0 5.0	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	3.0 15	_	1.0 5.0	3.0 15	_	6.0 30	μAdc
(f _{clock} = 16 kHz Depressed)	., 140 11645		6.0	-	60	_	20	60	_	120	
Standby Supply Cur Function of Cloc (No Keys Depres	k Frequency*	IDDS	5.0	* ·		I _{DDS} = 0.	09 μA/kH	z + 3.0 μA			μAdc

^{*}The formula given is for the typical characteristics only.

SWITCHING CHARACTERISTICS (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V _{DD}	Min	Тур	Max	Unit
Output Rise and Fall Times, D1 thru D4 (Figure 1)	t _r ,t _f	5.0		300		ns
Propagation Delay Time, Row or Column Input to Data Output (Figure 1)	tPLH, tPHL	5.0		1000	_	ns
Clock Pulse Frequency Range	PRF	3.0 to 6.0	4.0	16	80	kHz

FIGURE 1 - SWITCHING TIME WAVEFORMS

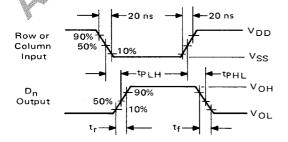


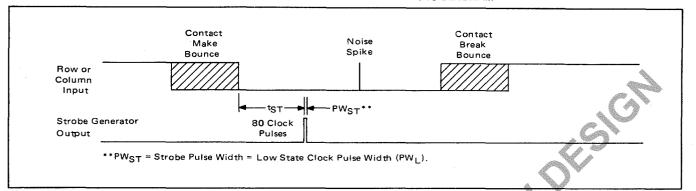
FIGURE 2 - TYPICAL STROBE PULSE DELAY TIMES

PRF Clock Frequency kHz	tST* Strobe Pulse Delay Time ms
4.0	20
8.0	10
16	5.0
32	2.5
80	1.0

^{*} $t_{ST} = (1/PRF) \bullet 80$, with PRF in kHz, t_{ST} in ms.



FIGURE 3 - STROBE GENERATOR TIMING DIAGRAM

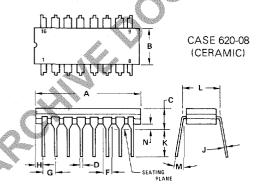


TRUTH TABLE

													400
	Inputs												
		R	ow			Colu	ımn				Οu	tput	S
Key**	R4	R3	R2	R1	C4	C3	C2	C1	D4	D3	D2	D1	Strobe
1	1	1	1	0	1	1	1	0	0	0	Q	1	کا
2	1	1	1	0	1	1	0	1	0	0		0	l V l
3	1	1	1	0	1	0	1	1	٥	0	1	1	ட
Α	1	1	1	0	0	1	1	1	1	1	0	0	0
4	1	1	0	1	1	1	1	0	0	1	0	0	ን
5	1	1	0	1	1	1	0	1	0 "	*	0	1	几
6	1	1	0	1	1	0	1	4	0	1	1	0	_T_
В	1	1	0	1	0	1	1	1	1	1	0	1	0
7	1	0	1	1	1	14	1	O	0	1	1	1	J
8	1	0	1	1	1		0	1	1	0	0	0	<u> </u>
9	1	0	1	1	1	0	1	1	1	0	0	1	J.
С	1	0	1	1	0	∌ 1	1	1	1	1	1	0	_0_
*	0	1	1	1	1	1	1	0	1	0	1	0	0
0	0	1	1.	T 1	1	1	0	1	0	0	0	0	J.
#	0	1	4	1	1	0	1	1	1	0	1	1	0
D	0	1	1	T	0	1	1	1	1	1	1	1	0
		ΑН	Oth	er Co	ombi	nat	ions		0	0	0	0	0

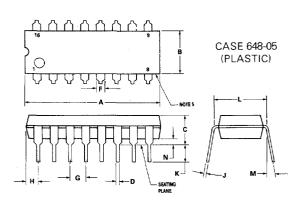
*See Figure 4 for keypad designation.

PACKAGE DIMENSIONS



	MILLIM	ETERS	INC	HES	
DIM	MIN	MIN MAX		MAX	
A	19.05	19.94	0.750	0.785	
В	6.10	7.49	0.240	0.295	
C	t	5.08	-	0.200	
D	0.38	0.53	0.015	0.021	
F	1.40	1.78	0.055	0.070	
G	2.54	BSC	0.100 BSC		
Н	0.51	1.14	0.020	0.045	
J	0.20	0.30	0.008	0.012	
K	3.18	4,32	0.125	0.170	
L	7.62	7.62 BSC		BSC	
М	_	15 ⁰	-	15 ⁰	
N	0.51	102	0.020	0.040	

- 1. LEADS WITHIN 0.13 mm (0.005) RADIUS 1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
 2. PACKAGE INDEX: NOTCH IN LEAD NOTCH IN CERAMIC OR INK DOT.
 3. DIM "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIM "A" AND "B" DO NOT INCLUDE GLASS RUN-OUT.
 5. DIM "F" MAY NARROW TO 0.76 mm (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.



	MILLIM	ETERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	18.80	21.34	0.740	0.840		
В	6.10	6.60	0.240	0.260		
C	4.06	5.08	0.160	0.200		
D	0.38	0.53	0.015	0.021		
F	1.02	1.78	0.040	0.070		
G	2.54	BSC	0.100 BSC			
H	0.38	2.41	0.015	0.095		
J	0.20	0.38	0.008	0.015		
K	2.92	3.43	0.115	0.135		
L	7.62	BSC	0.300	BSC		
M	0°	10°	0°	10°		
N	0.51	1.02	0.020	0.040		

- 1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE 1. Leads WI HIN 0.13 mm (0.005) RADIUS OF TR. POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
 2. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
 3. DIMENSION "B" DOES NOT INCLUDE MOLD ELACU.

- FLASH.

 4. "F" DIMENSION IS FOR FULL LEADS. "HALF"
 LEADS ARE OPTIONAL AT LEAD POSITIONS 1, 8,
- 9. AND 16.
- 5. ROUNDED CORNERS OPTIONAL.



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FIGURE 4 - TYPICAL KEYPAD INTERFACE APPLICATION

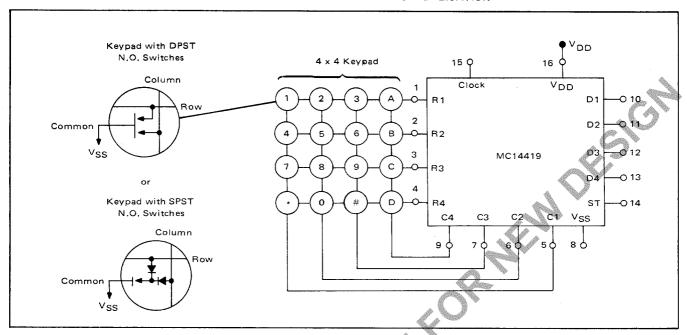
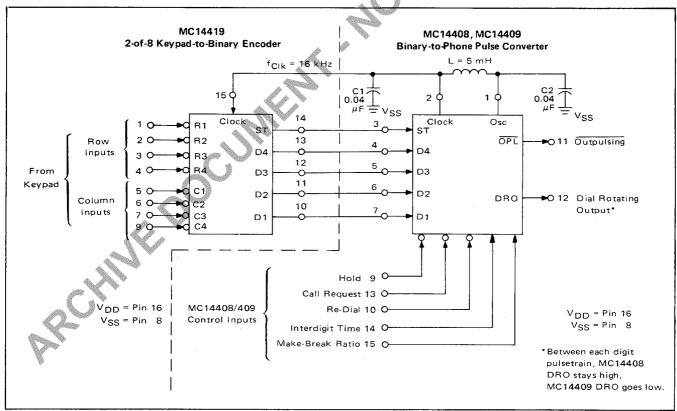


FIGURE 5 - PHONE DIALER SYSTEM



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